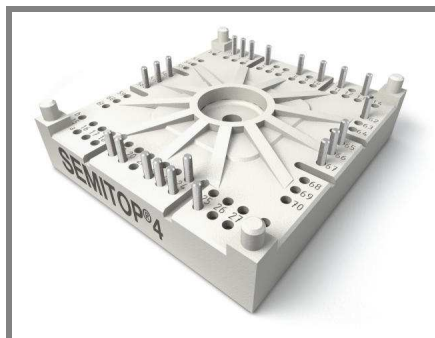


# SK50GD12T4T



SEMITOP® 4

## IGBT Module

SK50GD12T4T

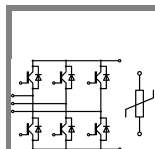
### Features

- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

### Typical Applications\*

### Remarks

- $V_{CE,sat}$ ,  $V_F$  = chip level value

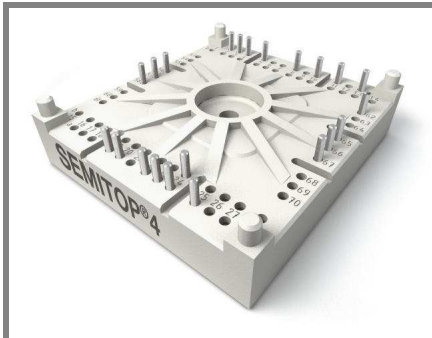


GD-T

Absolute Maximum Ratings		$T_s = 25\text{ °C}$ , unless otherwise specified		
Symbol	Conditions	Values		Units
<b>IGBT</b>				
$V_{CES}$	$T_j = 25\text{ °C}$	1200		V
$I_C$	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	75	A
		$T_s = 70\text{ °C}$	60	A
$I_{CRM}$	$I_{CRM} = 3 \times I_{Cnom}$	150		A
$V_{GES}$		± 20		V
$t_{psc}$	$V_{CC} = 800\text{ V}$ ; $V_{GE} \leq 15\text{ V}$ ; $T_j = 150\text{ °C}$ $V_{CES} < 1200\text{ V}$	10		µs
<b>Inverse Diode</b>				
$I_F$	$T_j = 175\text{ °C}$	$T_s = 25\text{ °C}$	60	A
		$T_s = 70\text{ °C}$	45	A
$I_{FRM}$	$I_{FRM} = 3 \times I_{Fnom}$	150		A
$I_{FSM}$	$t_p = 10\text{ ms}$ ; half sine wave $T_j = 150\text{ °C}$	265		A
<b>Module</b>				
$I_{t(RMS)}$				A
$T_{vj}$		-40 ... +175		°C
$T_{stg}$		-40 ... +125		°C
$V_{isol}$	AC, 1 min.	2500		V

Characteristics		$T_s = 25\text{ °C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT</b>					
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 1,7\text{ mA}$	5	5,8	6,5	V
$I_{CES}$	$V_{GE} = 0\text{ V}$ , $V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$	1,0		mA
		$T_j = 125\text{ °C}$			mA
$I_{GES}$	$V_{CE} = 0\text{ V}$ , $V_{GE} = 20\text{ V}$	$T_j = 25\text{ °C}$	600		nA
		$T_j = 125\text{ °C}$			nA
$V_{CE0}$		$T_j = 25\text{ °C}$	1,1	1,3	V
		$T_j = 150\text{ °C}$	1	1,2	V
$r_{CE}$	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	15		mΩ
		$T_j = 150\text{ °C}$	25		mΩ
$V_{CE(sat)}$	$I_{Cnom} = 50\text{ A}$ , $V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	1,85	2,05	V
		$T_j = 150\text{ °C}_{chiplev.}$	2,25	2,45	V
$C_{ies}$	$V_{CE} = 25$ , $V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	2,77		nF
$C_{oes}$			0,2		nF
$C_{res}$			0,16		nF
$Q_G$	$V_{GE} = -7V...+15V$	375		nC	
$R_{Gint}$	$T_j = 25\text{ °C}$	4		Ω	
$t_{d(on)}$	$R_{Gon} = 32\text{ Ω}$ $di/dt = 920\text{ A/µs}$	$V_{CC} = 600V$ $I_C = 50A$	63		ns
$t_r$			65		ns
$E_{on}$			8,3		mJ
$t_{d(off)}$	$R_{Goff} = 32\text{ Ω}$ $di/dt = 920\text{ A/µs}$	$T_j = 150\text{ °C}$ $V_{GE} = \pm 15\text{ V}$	521		ns
$t_f$			80		ns
$E_{off}$			5		mJ
$R_{th(j-s)}$	per IGBT	0,65		K/W	

# SK50GD12T4T



**SEMITOP® 4**

## IGBT Module

### SK50GD12T4T

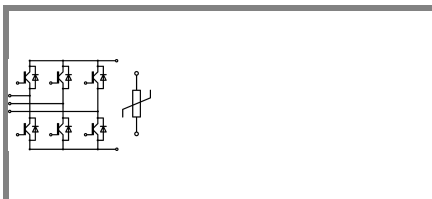
#### Features

- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

#### Typical Applications\*

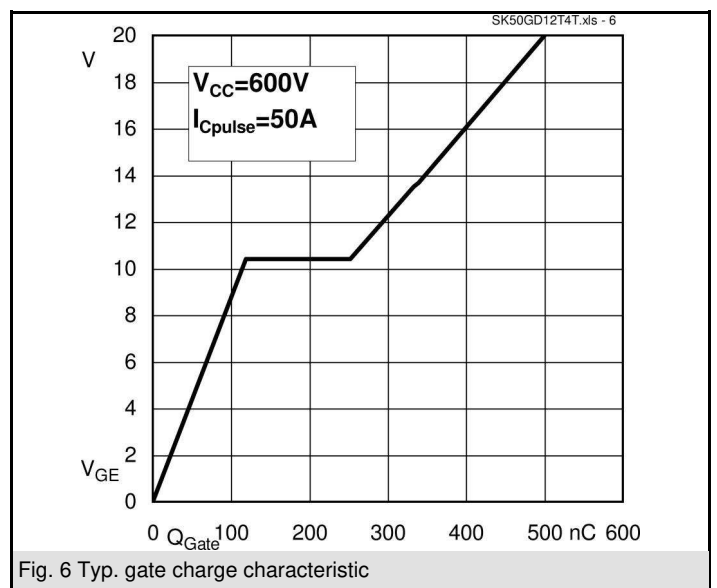
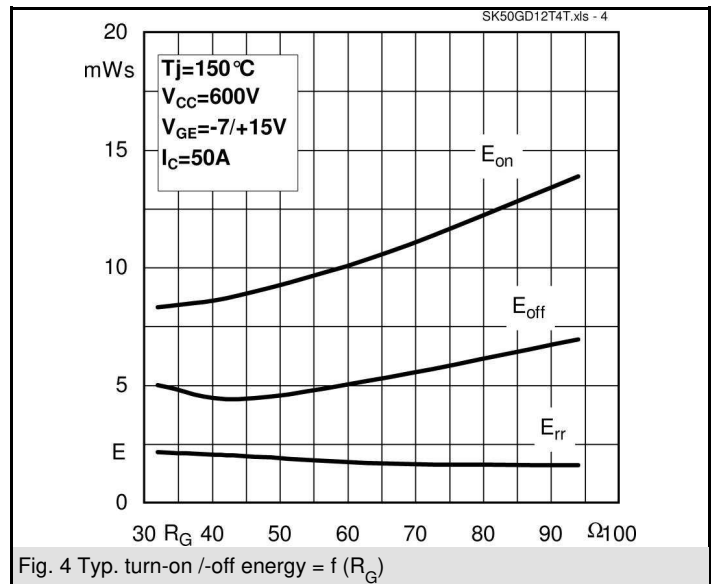
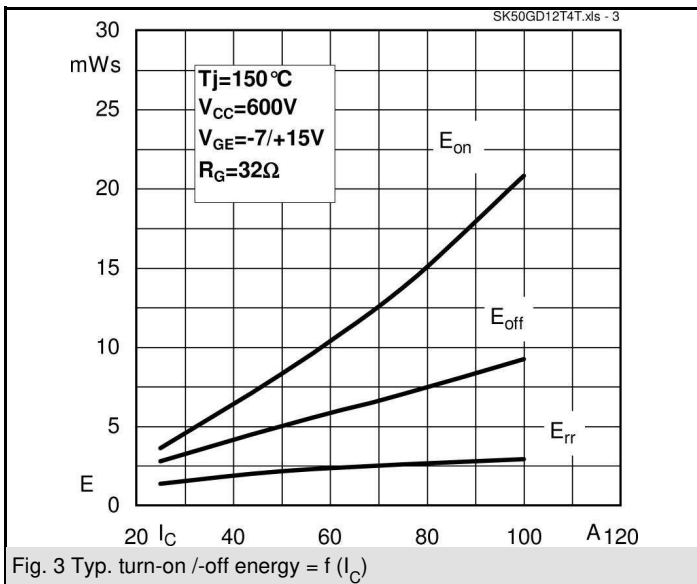
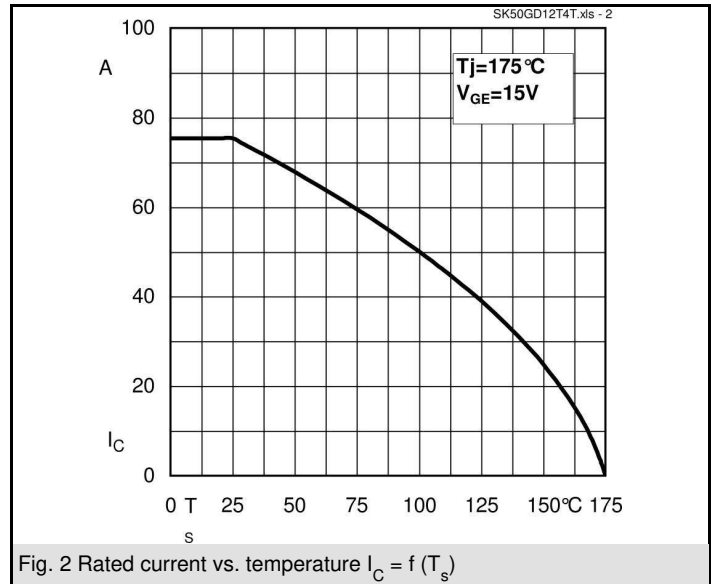
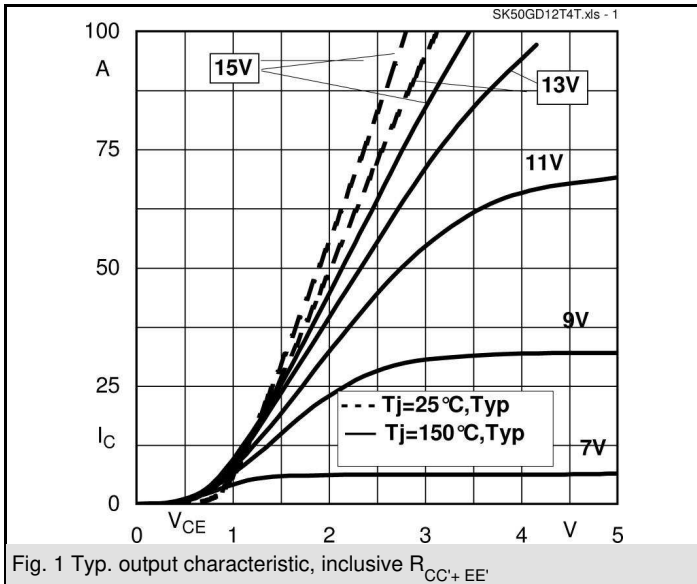
#### Remarks

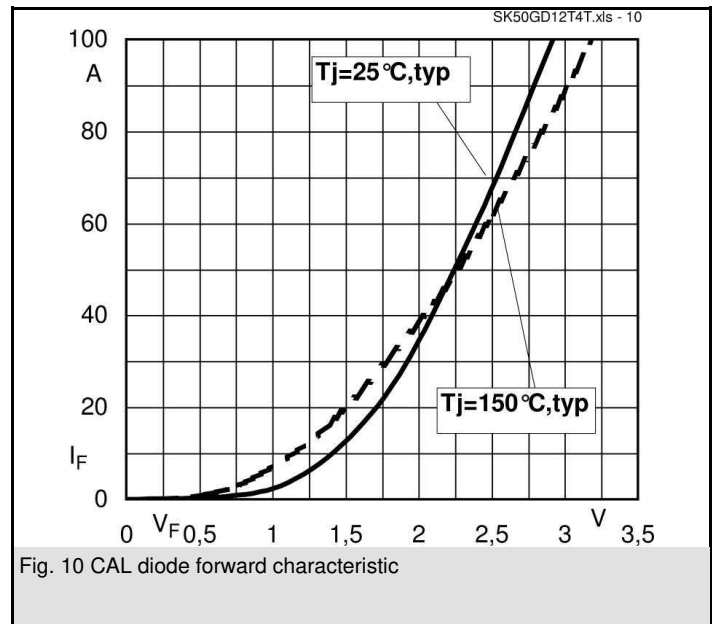
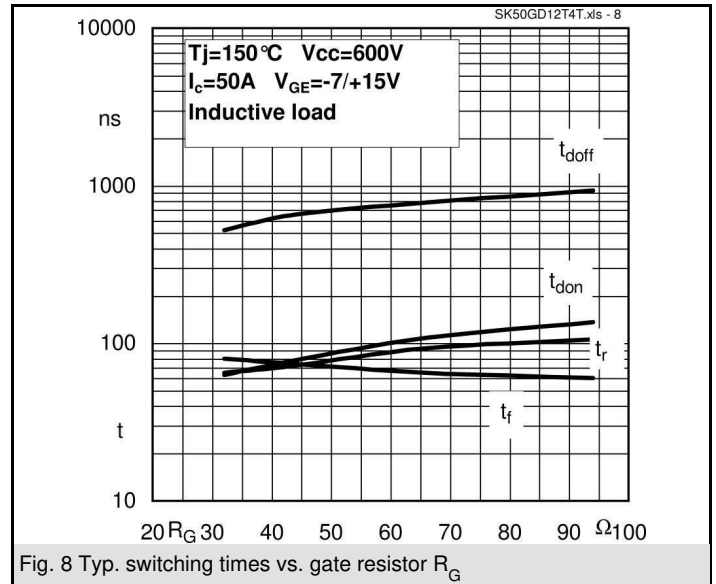
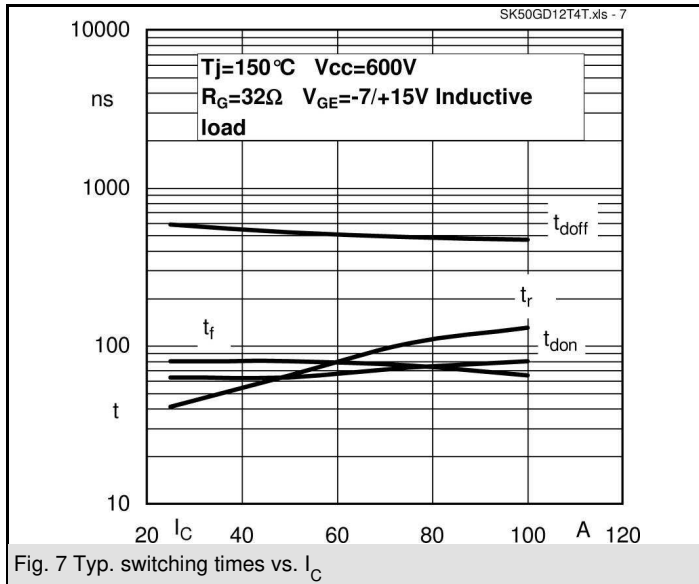
- $V_{CE,sat}$ ,  $V_F$  = chip level value

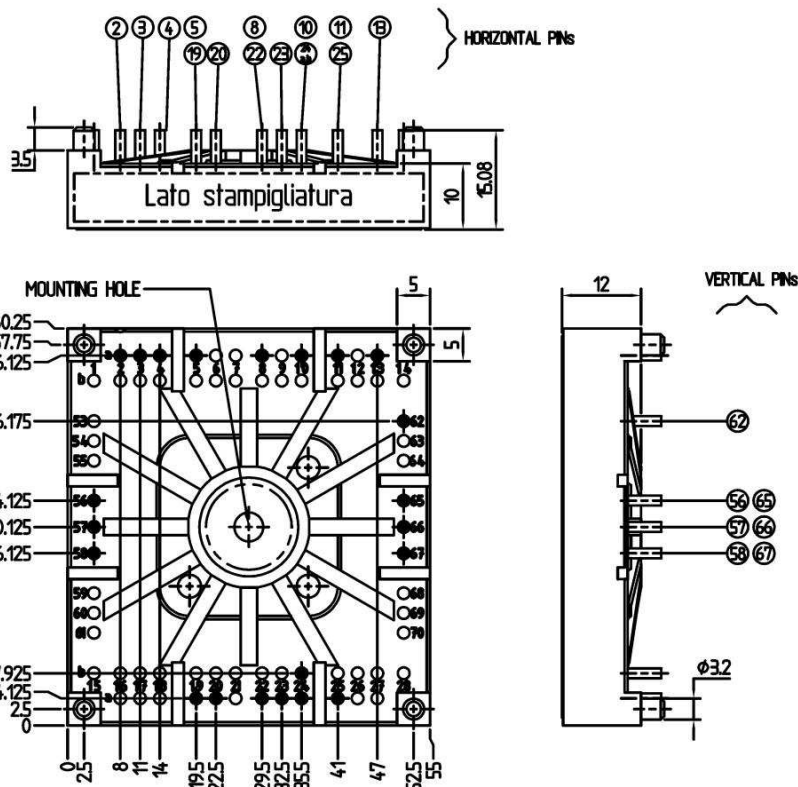


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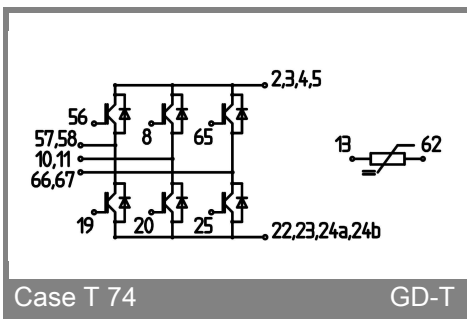
Characteristics			min.	typ.	max.	Units
<b>Inverse Diode</b>						
$V_F = V_{EC}$	$I_{Fnom} = 50 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$		2,2	2,55	V
		$T_j = 150 \text{ }^\circ\text{C}_{\text{chiplev.}}$		2,18	2,5	V
$V_{F0}$		$T_j = 25 \text{ }^\circ\text{C}$		1,3	1,5	V
		$T_j = 150 \text{ }^\circ\text{C}$		0,9	1,1	V
$r_F$		$T_j = 25 \text{ }^\circ\text{C}$		19	21	mΩ
		$T_j = 150 \text{ }^\circ\text{C}$		26	28	mΩ
$I_{RRM}$	$I_F = 50 \text{ A}$	$T_j = 150 \text{ }^\circ\text{C}$		30		A
$Q_{rr}$	$di/dt = 920 \text{ A}/\mu\text{s}$			7,2		μC
$E_{rr}$	$V_{CC} = 600\text{V}$			2,15		mJ
$R_{th(j-s)D}$	per diode			0,97		K/W
$M_s$	to heat sink		2,5		2,75	Nm
w				60		g
<b>Temperature sensor</b>						
$R_{100}$	$T_s = 100^\circ\text{C}$ ( $R_{25} = 5\text{k}\Omega$ )			493±5%		Ω







Case T74 (Suggested hole diameter for the solder pins in the circuit board: 2mm. Suggested hole diameter for the mounting pins in the circuit board: 3,6mm )



Case T 74

GD-T

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

### \*IMPORTANT INFORMATION AND WARNINGS

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